

Technical Data Data Sheet N1576, Rev. -Description:

800mA Low Dropout Positive Regulator

The SLR1117A is a low dropout, three terminals regulator designed to provide output current up to 1A. The device is available in an adjustable version and fixed output voltage of 1.8V, 2.5V and 3.3V. Dropout voltage of maximum of 1.5V is guaranteed at 1A output current. The quality of low dropout voltage and fast transient response make this device ideal for low voltage microprocessor applications. The SLR1117A requires output capacitance of a minimum of 10µF for stability. Built-in output current limiting provide maximal protection to the SLR1117A against fault conditions.

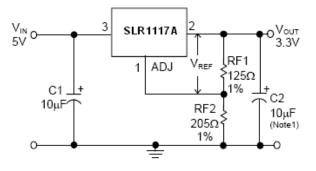
Features:

- Dropout Voltage 1.3V at 1A Output Current.
- Fast Transient Response.
- Line Regulation, typical at 0.015%.
- Load Regulation, typical at 0.1%.
- Current Limiting and Thermal Protection.
- Adjustable Output Voltage or Fixed 1.8V, 2.5Vand 3.3V.
- Standard 3-Pin Power Packages.

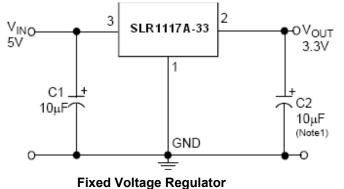
Applications:

- Active SCSI Terminators.
- Post Regulators for Switching Supplies.
- Battery Chargers.
- PC Add-On Card.

Typical application circuit:



Adjustable Voltage Regulator



V_{REF}=V_{OUT} - V_{ADJ}=1.25V (typ.) V_{OUT}=V_{REF} x (1+RF2/RF1)+ I_{ADJ} x RF2 I_{ADJ}=55µA (typ.)

- C1 needed if device is far away from filter capacitors.
- (2) C2 required for stability.

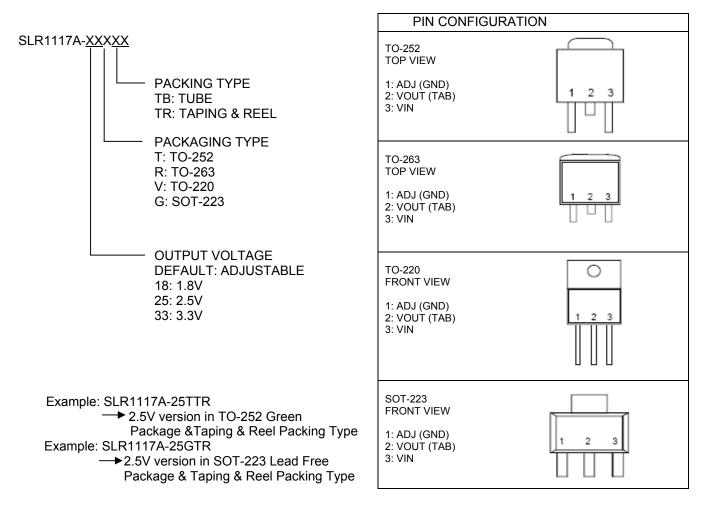
China - Germany - Korea - Singapore - United States
http://www.smc-diodes.com - sales@ smc-diodes.com



Technical Data Data Sheet N1576, Rev. -

800mA Low Dropout Positive Regulator

Ordering Information:



Marking Diagram:

Part No.	Marking
SLR1117A-18GTR	BS18G
SLR1117A-25GTR	BS25G
SLR1117A-33GTR	BS33G



800mA Low Dropout Positive Regulator

Absolute Maximum Ratings:

VIN pin to ADJ/GND pin	7V
Operating Temperature Range	
Maximum Junction Temperature	125°C
Storage Temperature Range	–65°C ~ 150°C
Lead Temperature (Soldering) 10 sec.	260°C
Thermal Resistance Junction to Case TO-252	12.5°C/W
ТО-263, ТО-220	3°C/W
SOT-223	15°C/W
Thermal Resistance Junction to Ambient TO-252	100°C/W
(Assume no ambient airflow, no heatsink) TO-263	60°C/W
SOT-223	155°C/W
ТО-220	50°C/W
Absolute Maximum Ratings are those values beyond which the life of a c	levice may be impaired.

Test Circuit

Refer to TYPICAL APPLICATION CIRCUIT.

Electrical Characteristics

PARAMETER	TEST CONDITIONS	MIN.	TYP.	MAX.	UNIT
	Tj=25°C	1.238	1.25	1.262	
Reference Voltage	0°C≤TJ≤125°C				V
Reference voltage	2.65V≤V _{IN} ≤7V	1.225	1.25	1.275	v
	10mA≤I _O ≤1A				
	SLR1117A-18, VIN=3.3V	1.78	1.80	1.82	
	SLR1117A-25, V _{IN} =5V	2.47	2.50	2.53	
	SLR1117A-33, VIN=5V	3.26	3.30	3.33	
Output Voltage	SLR1117A 0°C≤Tյ≤125°C	0.98Vout Vout	C≤TJ≤125°C	1.02Vout	V
	2.65V≤V _{IN} ≤7V		1.02/001		
	10mA≤I _O ≤1A				

(VIN=5V, TJ=25°C, IO=10mA, unless otherwise specified) (Note2)



800mA Low Dropout Positive Regulator

Electrical Characteristics (Continued)

PARAMETER	TEST CONDITIONS	MIN.	TYP.	MAX.	UNIT	
Line Regulation	2.65≤V _{IN} ≤7V, TJ=25°C		0.015	0.2	%V _{out}	
	0°C≤TJ≤125°C		0.035	0.2		
Load Regulation	TJ=25°C, IO=10mA~1A		0.1	0.3	%V _{out}	
Load Regulation	0°C≤TJ≤125°C		0.2	0.4	^{%0} VOUT	
Dropout Voltage	ΔV _{OUT} , ΔV _{REF} =1%, I _O =1A		1.3	1.5	V	
Current Limit		1			А	
Adjusted Dip Current (L.s.)	2.65≤V _{IN} ≤7V			120		
Adjusted Pin Current (I _{ADJ})	10mA≤I _O ≤1A		55		μΑ	
Adjusted Pin Current Change	2.65≤V _{IN} ≤7V		0.2	5		
(ΔI _{ADJ})	10mA≤l _O ≤1A		0.2		μA	
	I _O =0.5A	0.5			% Vout	
Temperature Stability	0°C≤Tj≤125°C		0.5		70 VOUI	
Minimum Load Current (Adj.)			5	10	mA	
Quiescent Current (Fixed Version)			10	14	mA	
RMS Output Noise (% of V _{OUT})	$10Hz \le f \le 10KHz$		0.003		%Vout	
Ripple Rejection Ratio	120Hz input ripple	60	72		dB	
	C _{OUT} =25µF					

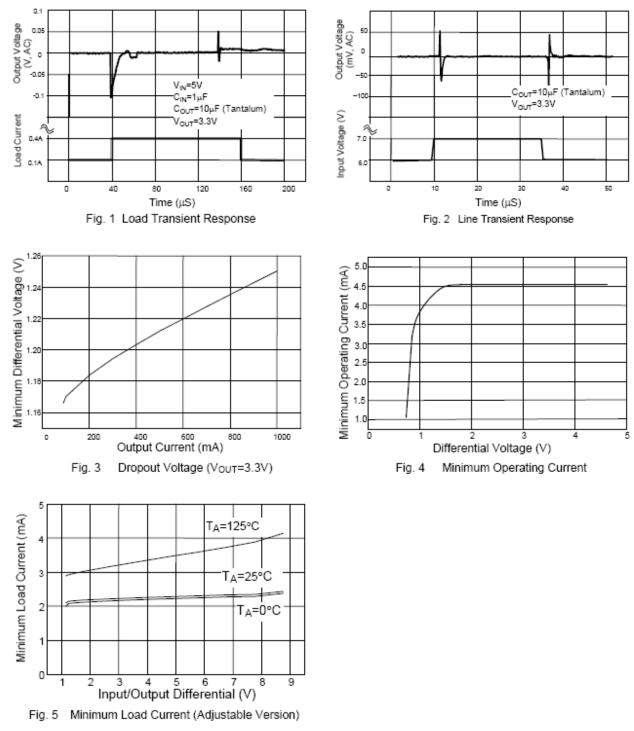
Note 1: To avoid output oscillation, aluminum electrolytic output capacitor is recommended and ceramic capacitor is not suggested.

Note 2: Specifications are production tested at T_A=25°C. Specifications over the -40°C to 85°C operating temperature range are assured by design, characterization and correlation with Statistical Quality Controls (SQC).



Technical Data Data Sheet N1576, Rev. -

800mA Low Dropout Positive Regulator



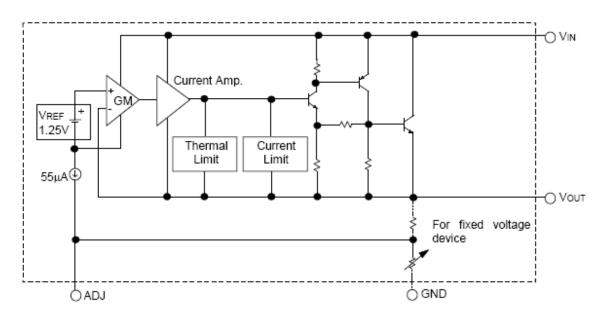
Typical Performance Characteristics

China - Germany - Korea - Singapore - United States http://www.smc-diodes.com - sales@ smc-diodes.com -



800mA Low Dropout Positive Regulator

Block Diagram



Pin Descriptions

- ADJ PIN Providing V_{REF} =1.25V (typ.) for adjustable V_{OUT} . V_{REF} = V_{OUT} - V_{ADJ} and I_{ADJ} =55µA (typ.) (GND PIN- Power ground.)
- VOUT PIN Adjustable output voltage.
- VIN PIN Power Input.



800mA Low Dropout Positive Regulator

Application Information

INPUT-OUTPUT CAPACITORS

Linear regulators require input and output capacitors to maintain stability. Input capacitor at 10μ F with a 10μ F aluminum electrolytic output capacitor is recommended.

POWER DISSIPATION

The SLR1117A obtains thermal-limiting circuitry, which is designed to protect the device against overload condition. For continuous load condition, maximum rating of junction temperature must not be exceeded. It is important to pay more attention in thermal resistance. It includes junction to case, junction to ambient. The maximum power dissipation of SLR1117A depends on the thermal resistance of its case and circuit board, the temperature difference between the die junction and ambient air, and the rate of airflow. The rate of temperature rise is greatly affected by the mounting pad configuration on the PCB, the board material, and the ambient temperature. When the IC mounting with good thermal conductivity is used, the junction temperature will be low even when large power dissipation applies. The power dissipation across the device is $P = I_{OUT} (V_{IN} - V_{OUT})$.

The maximum power dissipation is:

Fig. 8 Vout=1.25V Application Circuit

$$P_{MAX} = \frac{(T_{J-max} - T_A)}{P}$$

Where T_{J-max} is the maximum allowable junction temperature (125°C), and T_A is the ambient temperature suitable in application.

As a general rule, the lower temperature is, the better reliability of the device is. So the PCB mounting pad should provide maximum thermal conductivity to maintain low device temperature.

Application Examples

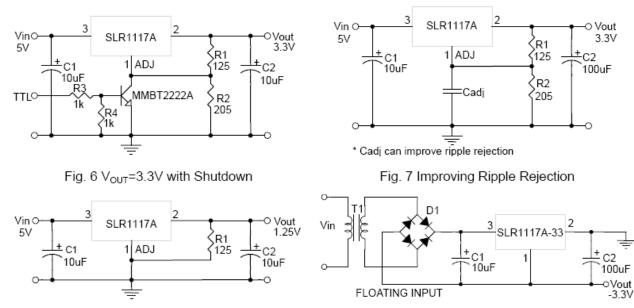


Fig. 9 Low Dropout Negative Supply

China - Germany - Korea - Singapore - United States http://www.smc-diodes.com - sales@ smc-diodes.com -

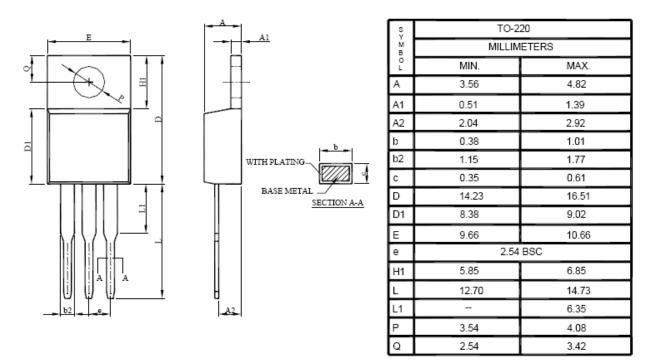


Technical Data Data Sheet N1576, Rev. -

800mA Low Dropout Positive Regulator

Physical Dimensions

TO-220 (unit: mm)



Note:

1. Refer to JEDEC TO-220AB.

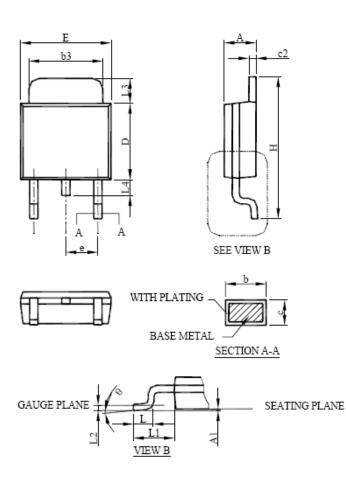
- 2. Dimension "E" does not include mold flash, protrusions or gate burrs. Mold flash, protrusion or gate burrs shall not exceed 6 mil per side.
- 3. Dimension "D1" does not include inter-lead flash or protrusions.
- 4. Controlling dimension is millimeter, converted inch dimensions are not necessarily exact.



Technical Data Data Sheet N1576, Rev. -

800mA Low Dropout Positive Regulator

TO-252 (unit: mm)



s v	TO-2	52-3L	
S Y M B O	MILLIMETERS		
Ľ	MIN.	MAX.	
А	2.19	2.38	
A1	0.00	0.13	
b	0.64	0.89	
b3	4.95	5.46	
с	0.46	0.61	
c2	0.46	0.89	
D	5.33	6.22	
E	6.35	6.73	
е	2.28 BSC		
Н	9.40	10.41	
L	1.40	1.78	
L1	2.67 REF		
L2	0.51 BSC		
L3	0.89	2.03	
L4		1.02	
θ	0°	8°	

Note:

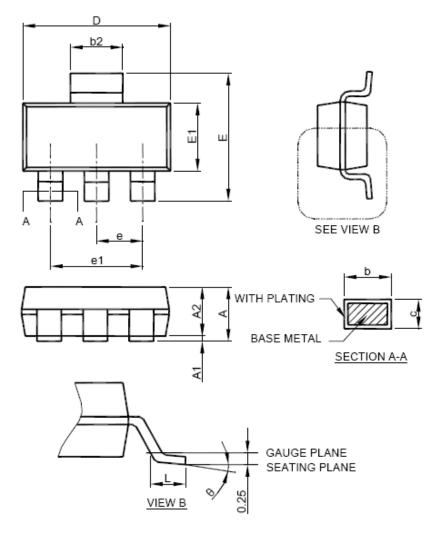
- 1. Refer to JEDEC TO-252AA and AB.
- 2. Dimension "E" do not include mold flash, protrusions or gate burrs. Mold flash, protrusion or gate burrs shall not exceed 6 mil per side.
- 3. Dimension "D" does not include inter-lead flash or protrusions.
- 4. Controlling dimension is millimeter, converted inch dimensions are not necessarily exact.



Technical Data Data Sheet N1576, Rev. -

800mA Low Dropout Positive Regulator

SOT-223(unit: mm)



s v	SOT-223		
s≻≯ во∟	MILLIMETERS		
0 L	MIN.	MAX.	
Α		1.80	
A1	0.02	0.10	
A2	1.55	1.65	
b	0.66	0.84	
b2	2.90	3.10	
с	0.23	0.33	
D	6.30	6.70	
E	6.70	7.30	
E1	3.30	3.70	
е	2.30 BSC		
e1	4.60 BSC		
L	0.90		
θ	0°	8°	

Note: 1. Refer to JEDEC TO-261AA.

- 2. Dimension "D" does not include mold flash, protrusions or gate burrs. Mold flash, protrusion or gate burrs shall not exceed 6 mil per side .
- 3. Dimension "E1" does not include inter-lead flash or protrusions.
- 4. Controlling dimension is millimeter, converted inch dimensions are not necessarily exact.

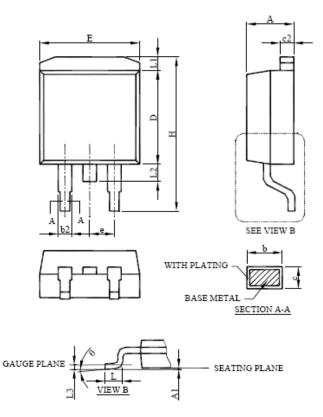
China - Germany - Korea - Singapore - United States http://www.smc-diodes.com - sales@ smc-diodes.com -



Technical Data Data Sheet N1576, Rev. -

800mA Low Dropout Positive Regulator

TO-263 (unit: mm)



S Y	TO-263-3L		
М В О	MILLIMETERS		
0 L	MIN.	MAX.	
А	4.06	4.83	
A1	0.00	0.25	
b	0.51	0.99	
b2	1.14	1.78	
с	0.38	0.74	
c2	1.14	1.65	
D	8.38	9.65	
E	9.65	10.67	
е	2.54 BSC		
Н	14.61	15.88	
L	1.78	2.79	
L1		1.68	
L2		1.78	
L3	0.25 BSC		
θ	0°	8°	

Note:

- 1. Refer to JEDEC TO-263AB.
- 2. Dimension "E" does not include mold flash, protrusions or gate burrs. Mold flash, protrusion or gate burrs shall not exceed 6 mil per side.
- 3. Dimension "D" does not include inter-lead flash or protrusions.
- 4. Controlling dimension is millimeter, converted inch dimensions are not necessarily exact.



Technical Data Data Sheet N1576, Rev. -

800mA Low Dropout Positive Regulator

DISCLAIMER:

1- The information given herein, including the specifications and dimensions, is subject to change without prior notice to improve product characteristics. Before ordering, purchasers are advised to contact the SMC - Sangdest Microelectronics (Nanjing) Co., Ltd sales department for the latest version of the datasheet(s).

2- In cases where extremely high reliability is required (such as use in nuclear power control, aerospace and aviation, traffic equipment, medical equipment, and safety equipment), safety should be ensured by using semiconductor devices that feature assured safety or by means of users' fail-safe precautions or other arrangement.

3- In no event shall SMC - Sangdest Microelectronics (Nanjing) Co., Ltd be liable for any damages that may result from an accident or any other cause during operation of the user's units according to the datasheet(s). SMC - Sangdest Microelectronics (Nanjing) Co., Ltd assumes no responsibility for any intellectual property claims or any other problems that may result from applications of information, products or circuits described in the datasheets.

4- In no event shall SMC - Sangdest Microelectronics (Nanjing) Co., Ltd be liable for any failure in a semiconductor device or any secondary damage resulting from use at a value exceeding the absolute maximum rating.

5- No license is granted by the datasheet(s) under any patents or other rights of any third party or SMC - Sangdest Microelectronics (Nanjing) Co., Ltd.

6- The datasheet(s) may not be reproduced or duplicated, in any form, in whole or part, without the expressed written permission of SMC - Sangdest Microelectronics (Nanjing) Co., Ltd.

7- The products (technologies) described in the datasheet(s) are not to be provided to any party whose purpose in their application will hinder maintenance of international peace and safety nor are they to be applied to that purpose by their direct purchasers or any third party. When exporting these products (technologies), the necessary procedures are to be taken in accordance with related laws and regulations.